## NSN 5961-00-450-1164

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Inclosure Material:	
Metal	
Overall Length:	
Between 0.170 inches and 0.210 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
Between 0.209 inches and 0.230 inches	
Internal Configuration:	
Field effect	
Electrode Internally-electrically Connected To Case:	
Gate	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
40.0 drain to source voltage and -40.0 gate to source voltage	
Current Rating Per Characteristic:	
10.00 milliamperes gate current	
Power Rating Per Characteristic:	
360.0 milliwatts total power dissipation	
Maximum Operating Tempurature Per Measurement Point:	
175.0 degrees celsius ambient air	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type	data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type	data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/431 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	